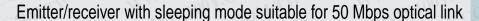
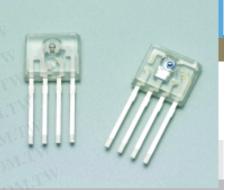
Red LED/Photo IC for optical link L8045/S8046





L8045 and S8046 are optical communication devices designed for POF (Plastic Optical Fiber) data links. L8045 is a highly reliable, high-power LED that emits red light with a peak at 650 nm optimized for POF. A mini-lens is molded on the package for efficient coupling to a POF. When used with our recommended driver circuit, a 50 Mbps transmitter can be configured at low cost. S8046 is a high sensitivity, high-speed photo IC that receives signals at 50 Mbps and covers a wide dynamic range of 21.5 dB. The output is TTL compatible. S8046 also features a sleeping mode in which operation automatically switches to low power dissipation mode when no light is input and switches back to normal operation mode when light is input from the optical fiber. The internal IC checks which mode is currently selected and this check signal is available from the mode output terminal. Current consumption in sleeping mode is approximately 1/400th that of normal operation mode.

Features

L8045

- Peak wavelength: 650 nm
- High reliability
- High output

S8046

- Sleeping mode (low power dissipation)
- 4 to 50 Mbps
- Monolithic photo IC
- Optimum operation when used with L8045
- High reliability
- TTL output
- Wide dynamic range

Applications

High-speed data transmission even under poor environmental conditions with high noise

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L8045

Absolute	maximum	ratings	(Ta=25 °C)	
Absolute	III a x IIII u III	Tatiliya	(1a-23 C)	

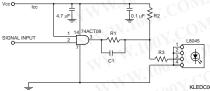
Parameter	Symbol	Value	Unit
Forward current	lF	40	m A
Reverse voltage	VR	5	V
Power dissipation *1	Pmax	250	m W
Operating temperature	Topr	-40 to +85	°C
Storage temperature	Tstg	-40 to +85	°C
Soldering		230 °C, 5 s, at least 1.8 mm away from package surface	-x+11

^{*1:} Derate power dissipation at a rate of -1.75 mW/°C above Ta=25 °C

 Electrical and optical characteristics 	(1a=25 C)	- 1 1 1 - 2				
Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Data rate	fD	NRZ	DC		50	Mbps
Forward voltage	VF	IF=20 mA	1 (JU)	1.9	2.3	V
Reverse current	IR	VR=5 V	7	4 - 4	10	μA
Peak wavelength	λρ	IF=20 mA		650	-	nm
Spectral half width (FWHM)	Δλ	IF=20 mA	1.5	20	-	nm
Fiber-coupled optical output	Po	*2, 3, 4	-13	111-2	-8	dBm
Rise time at pulse drive	tr	*2, 3, 4 20 to 80 %	- KF	-	8	ns
Fall time at pulse drive	tf	* ^{2, 3, 4} 80 to 20 %	U(I) F .	-	8	ns
Pulse distortion	ΔΤ	*2, 3, 4	-3	DAS.	+1	ns
Jitter	Λti	*2, 3, 4	00.1	1	3	ns

^{*2:} Input is a pseudo-random bi-phase signal at 50 Mbps

 $^{^*}$ 3: Measured with the recommended driver circuit shown below. (Measurement conditions: Vcc=4.5 to 5.5 V, R1=750 $\Omega_{
m s}$



^{*4:} Average value (duty ratio 50 %) measured by using a plastic fiber of φ1 mm. SI-POF and NA=0.5 (GH4001 made by

^{2:} The center of the optical fiber is aligned with the center of the lens on the package. The distance between the fiber end and the lens is 0.1 mm.



^{1:} A bypass capacitor (0.1 μF) and another capacitor (4.7 μF) are connected between Vcc and GND at a position within 3 mm

Red LED/Photo IC for optical link L8045/S8046

S8046

■ Absolute maximum ratings (Ta=25 °C)

Parameter	Symbol	Value	Unit
Supply voltage	Vcc	-0.5 to +7.0	V
Output voltage	Vo	-0.5 to Vcc+0.5	V
Output current	lo	1010	mA
Power dissipation	-1 C()NP	250 *5	mW
Operating temperature	Topr	-40 to +85	°C
Storage temperature	Tstg	-40 to +85	°C
Soldering	17. T	230 °C, 5 s, at least 1.8 mm away from package surface	-

^{*5:} Derate power dissipation at a rate of -1.75 mW/°C above Ta=25 °C

■ Electrical and optical characteristics (Ta=25 °C, Vcc=4.5 to 5.5 V)

	Parameter	Symbol	Condition	Min.	Тур	Max.	Unit
Data rate		fD	bi-phase signal	4	~<1-CU	50	Mbps
Current	consumption (in operation mode)	Icco	*6, 7	11	10 r.	40	mA
Current	consumption (in sleeping mode)	lccs Pimax	Pin= -∞ *6, 7, 9, 10	-8	10051.00	100	μA dBm
Minimum	n overload						
Minimum	receiver input power	Pimin	* 6, 7, 9, 10		= = 7	-29.5	⊲ dBm
	H level output voltage	Voh	Ioh= -150 μA*6, 7	2.7	1002	1.12	V
Output	L level output voltage	Vol	Iol=1.6 mA *6,7	- (N)		0.4	V
voltage Rise time Fall time	Rise time	tr	20 to 80 % *6,7	1/7	-110 X	5	ns
	Fall time	tf		- 111	W	5	ns
Pulse width distortion		Δt	*6, 7	-4	-1-100	+8	ns
Jitter		Δtj	*6, 7	1	1115	5	ns
Operation mode to sleeping mode switching input power		Psl	*6, 7, 9	-7//	- 10	-33	dBm
Sleeping mode to operation mode switching input power		Pop	*6, 7, 9	1	W. Mars	-30	dBm
Sleeping mode to operation mode switching time		tso	*6	- 1/1	1	200	μs
Operation	mode to sleeping mode switching time	tos	*6	-		500	μs
Mode	H level voltage	Vmh	*11	3.0	V * '-	1007.	V
output	L level voltage	VmI	*11		- TIN	0.5	V

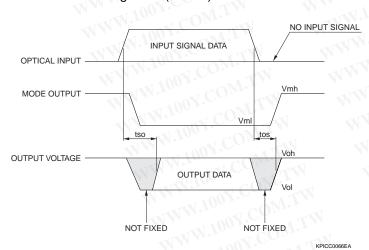
^{*6:} Input is a pseudo-random bi-phase signal at 50 Mbps.

*11: "H" in sleeping mode, "L" in operation mode

Note)

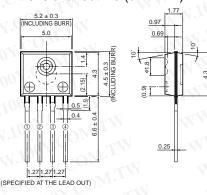
- 3: A bypass capacitor (0.1 µF) and another capacitor (4.7 µF) are connected between Vcc and GND at a position within 3 mm from the lead
- 4: The center of the optical fiber is aligned with the center of the lens on the package. The distance between the fiber end and the lens is 0.1 mm.
- 5: Output becomes undefined at a baud rate less than 4 Mbps.

■ Mode switching chart (S8046)



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■ Dimensional outline (unit: mm)





lo.	L8045	S8046		
	CATHODE	MODEOUT		
<1	CATHODE	GND		
M	ANODE	Vout		
	CATHODE	Vcc		
	Ń	CATHODE		

noted: ±0.1, ±0.2° Shaded area indicates burn Values in parentheses indicate reference value

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^{*7:} CL=5 pF (including parasitic capacitance of probes, connectors and PC board)

^{*8:} Optical input signal is generated by our standard signal generator.

^{*9:} Average value (at 50 % duty ratio) *10: Pe=10⁻⁹